

MOSFETs Silicon P-Channel MOS (U-MOSVI)

# SSM3J168F

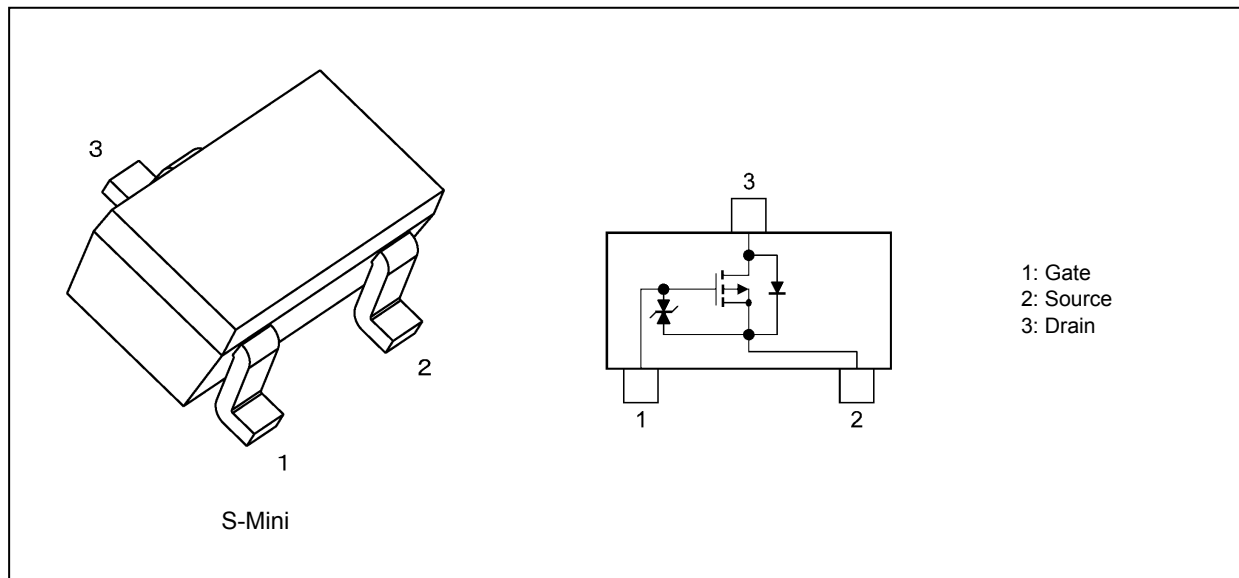
### 1. Applications

- High-Speed Switching
- Analog Switches
- Interfacing

### 2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) 4.0 V drive
- (3) Low drain-source on-resistance
  - :  $R_{DS(ON)} = 1.6 \Omega$  (typ.) ( $V_{GS} = -4.0 \text{ V}$ )
  - $R_{DS(ON)} = 1.4 \Omega$  (typ.) ( $V_{GS} = -4.5 \text{ V}$ )
  - $R_{DS(ON)} = 1.3 \Omega$  (typ.) ( $V_{GS} = -10 \text{ V}$ )

### 3. Packaging and Pin Assignment



### 4. Orderable part number

Orderable part number	AEC-Q101	Note
SSM3J168F,LF	—	General Use
SSM3J168F,LXGF	YES (Note 1)	Unintended Use (Note 1)
SSM3J168F,LXHF	YES	Automotive Use

Note 1: For more information, please contact our sales or use the inquiry form on our website.

Start of commercial production  
2016-11

### 5. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	-60	V
Gate-source voltage	$V_{GSS}$	-20/+10	
Drain current (DC) (Note 1)	$I_D$	-400	mA
Drain current (pulsed) (Note 1)	$I_{DP}$	-800	
Power dissipation (Note 2)	$P_D$	600	mW
Power dissipation $t \leq 1\text{ s}$ (Note 2)		1200	
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Ensure that the channel temperature does not exceed  $150\text{ }^\circ\text{C}$ .

Note 2: Device mounted on a  $25.4\text{ mm} \times 25.4\text{ mm} \times 1.6\text{ mm}$  FR4 glass epoxy board (Cu pad:  $645\text{ mm}^2$ )

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.

Note: The channel-to-ambient thermal resistance,  $R_{th(ch-a)}$ , and the drain power dissipation,  $P_D$ , vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

### 6. Electrical Characteristics

#### 6.1. Static Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = -16\text{ V}/+10\text{ V}$	—	—	$\pm 10$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = -60\text{ V}, V_{GS} = 0\text{ V}$	—	—	-10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1\text{ mA}, V_{GS} = 0\text{ V}$	-60	—	—	V
Drain-source breakdown voltage (Note 1)	$V_{(BR)DSX}$	$I_D = -1\text{ mA}, V_{GS} = 10\text{ V}$	-50	—	—	
Gate threshold voltage (Note 2)	$V_{th}$	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-0.8	—	-2.0	
Drain-source on-resistance (Note 3)	$R_{DS(ON)}$	$I_D = -100\text{ mA}, V_{GS} = -4.0\text{ V}$	—	1.6	2.0	$\Omega$
		$I_D = -100\text{ mA}, V_{GS} = -4.5\text{ V}$	—	1.4	1.9	
		$I_D = -200\text{ mA}, V_{GS} = -10\text{ V}$	—	1.3	1.55	

Note 1: If a reverse bias is applied between gate and source, this device enters  $V_{(BR)DSX}$  mode. Note that the drain-source breakdown voltage is lowered in this mode.

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (-1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ .

Take this into consideration when using the device.

Note 3: Pulse measurement.

#### 6.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = -10\text{ V}, V_{GS} = 0\text{ V},$ $f = 1\text{ MHz}$	—	82	—	pF
Reverse transfer capacitance	$C_{rss}$		—	5.5	—	
Output capacitance	$C_{oss}$		—	13	—	
Switching time (turn-on time)	$t_{on}$	$V_{DD} = -30\text{ V}, I_D = -0.1\text{ A},$ $V_{GS} = 0\text{ to }-10\text{ V}, R_G = 50\text{ }\Omega$ Duty $\leq 1\%$ , $V_{IN}$ : $t_r, t_f < 5\text{ ns}$ , Common source	—	4.3	—	ns
Switching time (turn-off time)	$t_{off}$		—	31.7	—	

#### 6.3. Switching Time Test Circuit

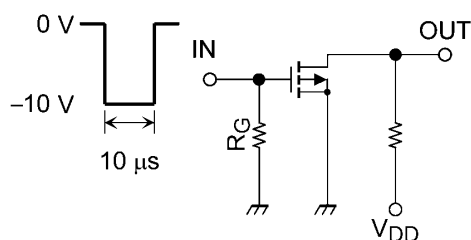


Fig. 6.3.1 Switching Time Test Circuit

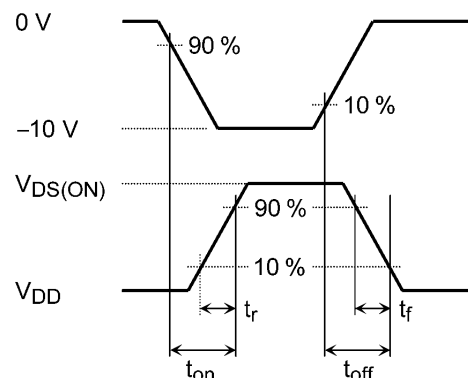


Fig. 6.3.2 Input Waveform/Output Waveform

#### 6.4. Gate Charge Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )

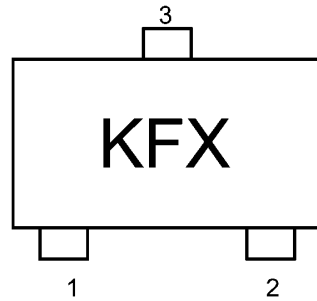
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} = -48\text{ V}, I_D = -0.4\text{ A},$ $V_{GS} = -10\text{ V}$	—	3.0	—	nC
Gate-source charge 1	$Q_{gs1}$		—	0.4	—	
Gate-drain charge	$Q_{gd}$		—	1.1	—	

## 6.5. Source-Drain Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$ )

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage (Note 1)	$V_{DSF}$	$I_D = 400\text{ mA}$ , $V_{GS} = 0\text{ V}$	—	0.87	1.2	V

Note 1: Pulse measurement.

## 7. Marking



## 8. Characteristics Curves (Note)

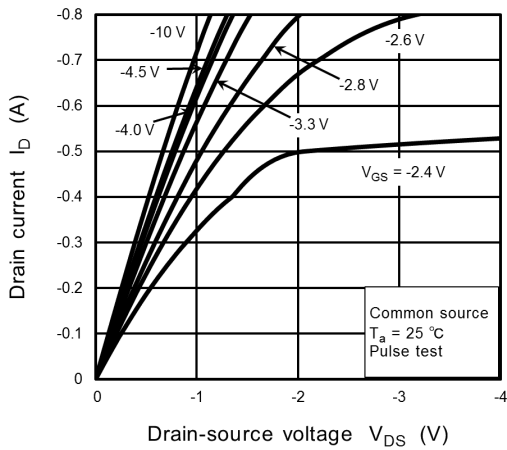


Fig. 8.1  $I_D - V_{DS}$

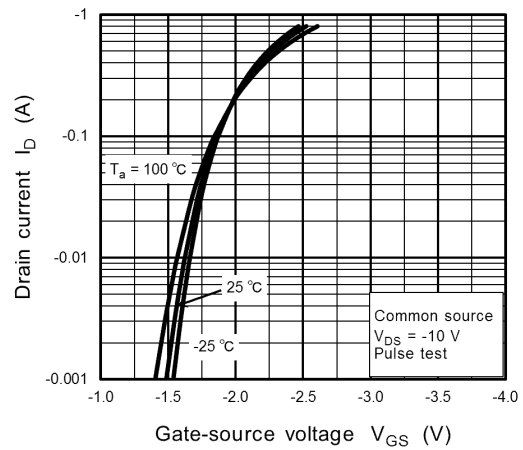


Fig. 8.2  $I_D - V_{GS}$

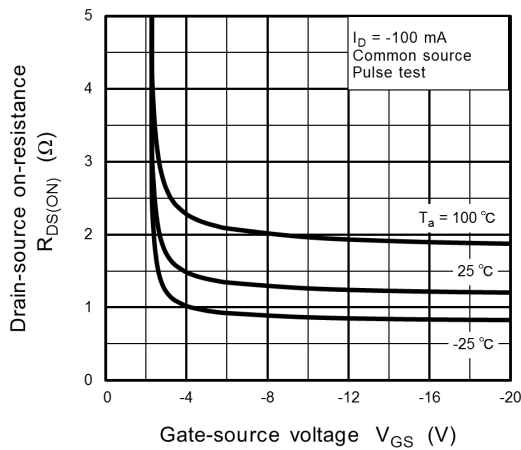


Fig. 8.3  $R_{DS(ON)} - V_{GS}$

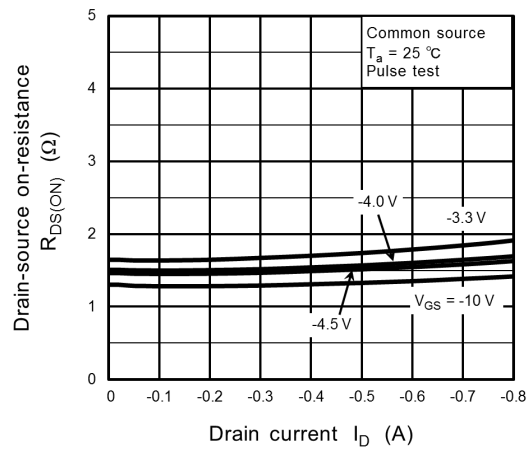


Fig. 8.4  $R_{DS(ON)} - I_D$

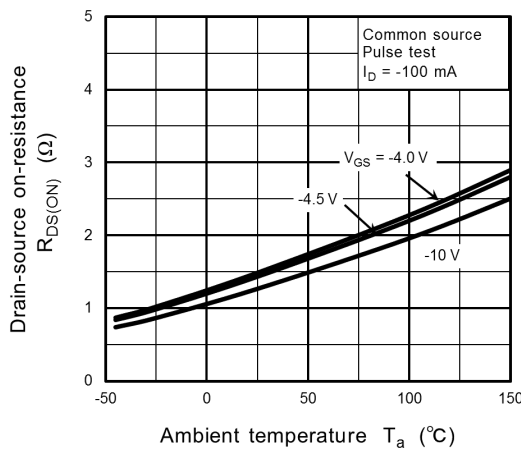


Fig. 8.5  $R_{DS(ON)} - T_a$

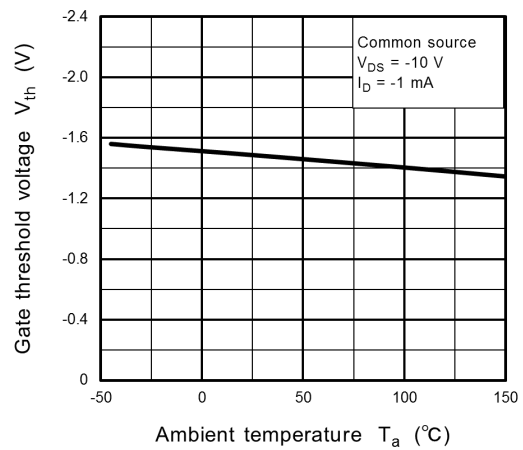
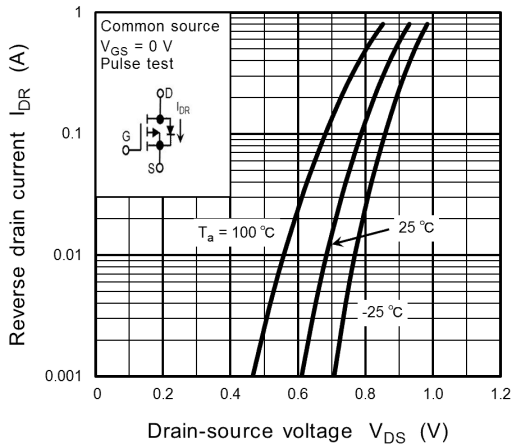
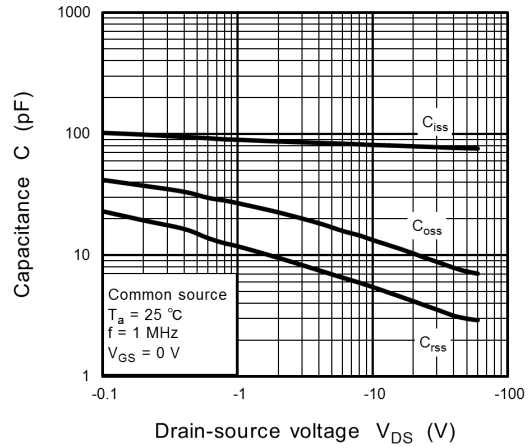


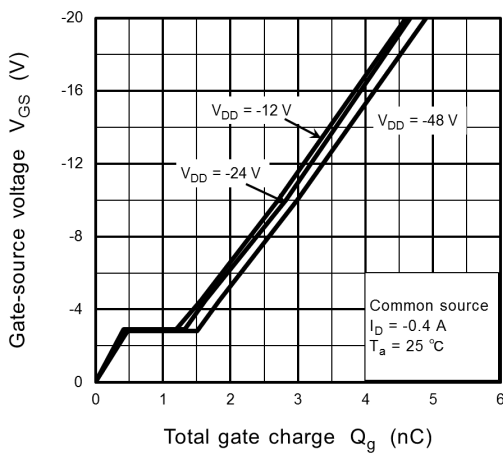
Fig. 8.6  $V_{th} - T_a$



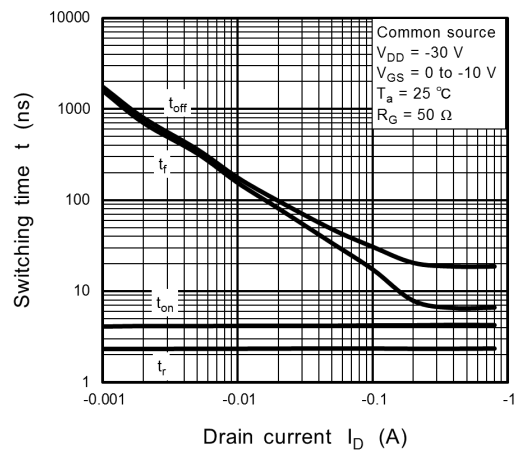
**Fig. 8.7  $I_{DR} - V_{DS}$**



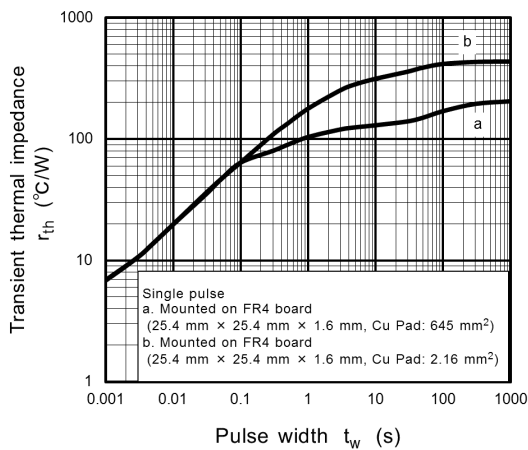
**Fig. 8.8  $C - V_{DS}$**



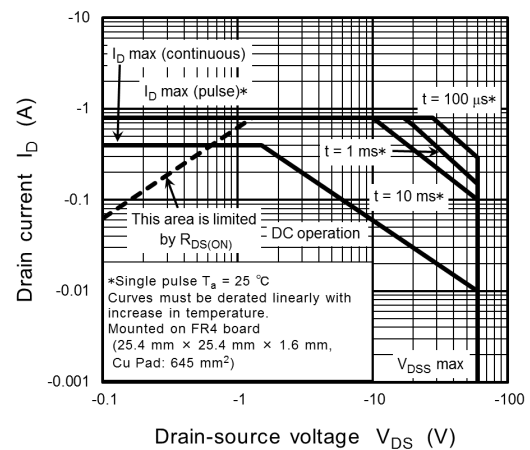
**Fig. 8.9 Dynamic Input Characteristics**



**Fig. 8.10  $t - I_D$**



**Fig. 8.11  $r_{th} - t_w$**



**Fig. 8.12 Safe Operating Area**

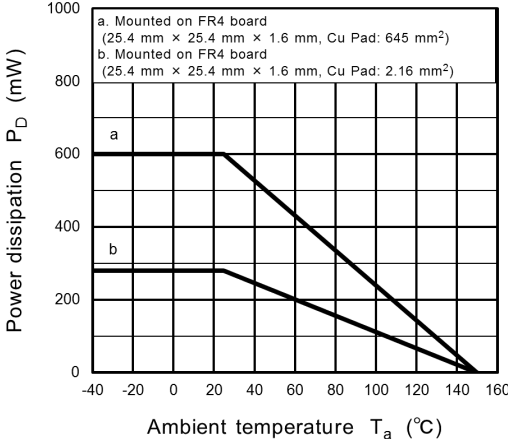
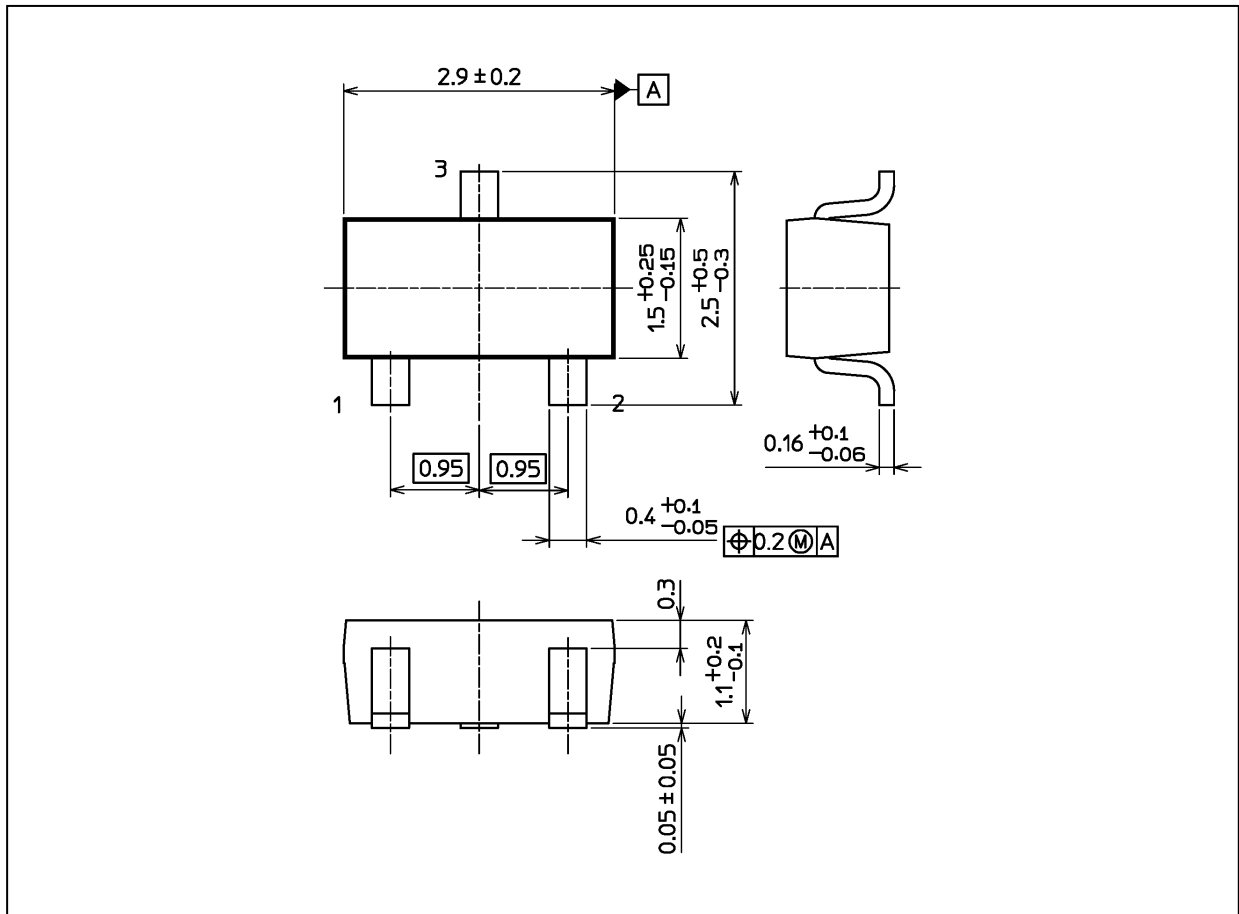


Fig. 8.13  $P_D - T_a$

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

## Package Dimensions

Unit: mm



Weight: 12 mg (typ.)

Package Name(s)
JEDEC: SOT-346
Nickname: S-Mini



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